

TOSHIBA Photocoupler GaAs Ired & Photo-MOS FET

## TLP3540

Memory Testers

Logic IC Testers

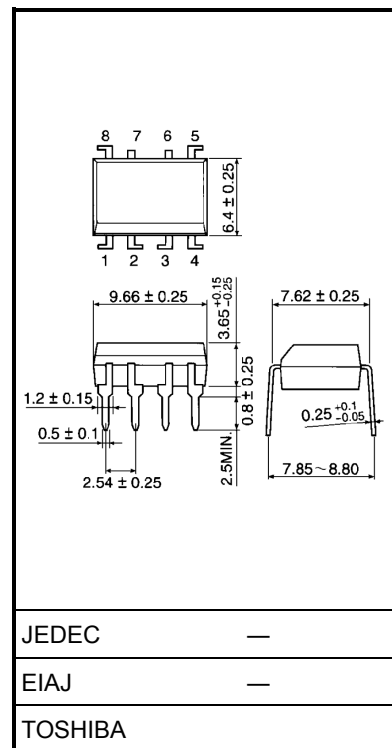
Data Recording Equipment

Measuring Equipment

Unit in mm

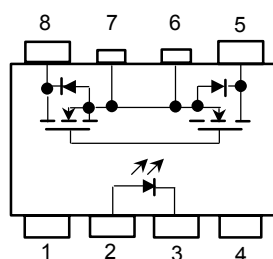
TLP3540 is a photorelay and consists of a GaAs infrared emitting diode optically coupled to a photo-MOSFET in a 8-pin DIP package (DIP8). This photorelay has characteristics of low-on resistance when it turns on. It is suitable for 48 V power line on / off switches.

- 1-form-A
- Peak off-state voltage: 60V(min.)
- Trigger LED current: 5mA(max.)
- On-state current: 2A(max.)
- On-state resistance: 120mΩ(max.)
- Isolation voltage: 1500V<sub>rms</sub>(min.)



Weight: 0.54 g

### Pin Configuration (top view)



- 1 : NC
- 2 : Anode
- 3 : Cathode
- 4 : NC
- 5 : Drain
- 6 : Source (shorten a pin)
- 7 : Source (shorten a pin)
- 8 : Drain

## Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I <sub>F</sub>	50	mA
	Reverse voltage	V <sub>R</sub>	6	V
	Junction temperature	T <sub>j</sub>	125	°C
Detector	Off-state output voltage	V <sub>OFF</sub>	60	V
	On-state current	I <sub>ON</sub>	2	A
	Junction temperature	T <sub>j</sub>	125	°C
Storage temperature		T <sub>stg</sub>	–55~125	°C
Operating temperature		T <sub>opr</sub>	–20~85	°C
Lead solder temperature (10 s)		T <sub>sol</sub>	260	°C
Isolation voltage (AC, 1 min., R.H.≤ 60%) (Note 1)		BV <sub>S</sub>	1500	V <sub>rms</sub>

(Note 1): Device considered a two-terminal device: Pins 1, 2, 3 and 4 shorted together and pins 5 and 8 shorted together.

## Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V <sub>OFF</sub>	—	—	48	V
Forward current	I <sub>F</sub>	10	—	30	mA
On-state current	I <sub>ON</sub>	—	—	2	A
Operating temperature	T <sub>opr</sub>	25	—	50	°C

## Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 20 mA	1.0	1.2	1.4	V
	Reverse voltage	I <sub>R</sub>	V <sub>R</sub> = 6 V	—	—	10	μA
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	—	15	—	pF
Detector	Off-state current	I <sub>OFF</sub>	V <sub>OFF</sub> = 20V, Ta = 50°C	—	1.0	4.0	nA
	Capacitance	C <sub>OFF</sub>	V = 0, f = 1MHz	—	600	1400	pF

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Trigger LED current	I <sub>FT</sub>	I <sub>ON</sub> = 1 A	—	—	5	mA
On-state resistance	R <sub>ON</sub>	I <sub>ON</sub> = 1 A, I <sub>F</sub> = 10mA	—	—	0.12	Ω

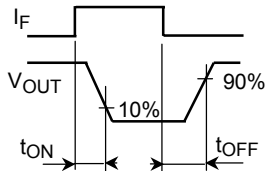
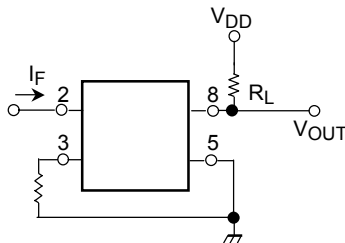
Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	$C_S$	$V_S = 0V, f = 1\text{ MHz}$	—	0.8	—	pF
Isolation resistance	$R_S$	$V_S = 500\text{ V}, \text{R.H.} \leq 60\%$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation voltage	$BV_S$	AC, 1 minute	1500	—	—	$V_{rms}$
		AC, 1 second (in oil)	—	3000	—	
		DC, 1 minute (in oil)	—	3000	—	Vdc

Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Turn-on time	$t_{ON}$	$R_L = 200\Omega$ $V_{DD} = 20\text{ V}, I_F = 15\text{ mA}$ (Note2)	—	—	5	ms
Turn-off time	$t_{OFF}$		—	—	3	

(Note 2): Switching time test circuit



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